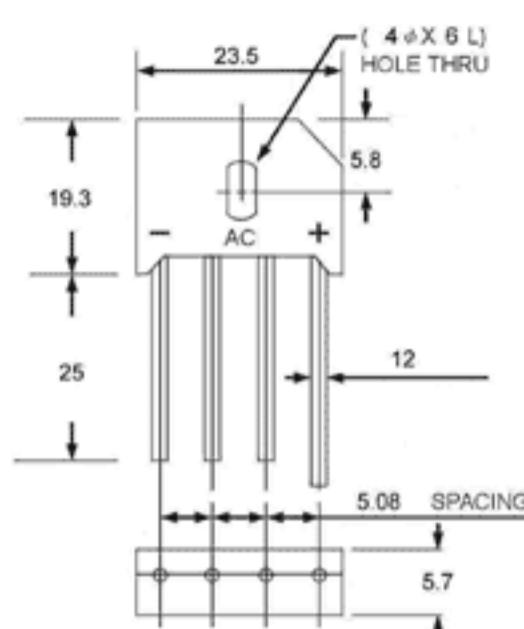


SILICON BRIDGE RECTIFIERS	REVERSE VOLTAGE - 50 to 1000 Volts FORWARD CURRENT - 4A / 6A / 8A Amperes
FEATURES	 <p>Dimensions in inches</p>

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	TBU4A	TBU4B	TBU4D	TBU4G	TBU4J	TBU4K	TBU4M	UNIT		
	TBU6A	TBU6B	TBU6D	TBU6G	TBU6J	TBU6K	TBU6M			
	TBU8A	TBU8B	TBU8D	TBU8G	TBU8J	TBU8K	TBU8M			
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V		
Maximum RMS Bridge Input Voltage	35	70	140	280	420	560	700	V		
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V		
Maximum Average Forward Rectified Output Current at $T_c=100^\circ\text{C}$ $T_A=50^\circ\text{C}/40^\circ\text{C}/45^\circ\text{C}$	TBU4	4.0	TBU6	6.0	TBU8	8.0	A			
4.0		6.0		6.0		A				
150		170		200		A				
1.0		1.0		1.0		V				
10		10		10		μA				
Maximum Instantaneous Forward Voltage Drop per Element at 4.0A/6.0A/8.0A								mA		
Maximum Reverse Leakage at rated DC Blocking Voltage per Element $T_A=25^\circ\text{C}$ $T_c=100^\circ\text{C}$										
Operating and Storage Temperature Range T_J, T_{STG}	-40 to +125							°C		